Rev.1.00



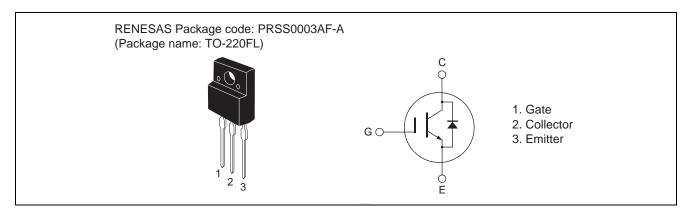
RJH60V1BDPP-M0

600V - 8A - IGBT R07DS0759EJ0100 **Application: Inverter** May 25, 2011

Features

- Short circuit withstand time (6 µs typ.)
- Low collector to emitter saturation voltage $V_{CE(sat)} = 1.6 \text{ V typ.}$ (at $I_C = 8 \text{ A}$, $V_{GE} = 15 \text{ V}$, $Ta = 25^{\circ}C$)
- Built in fast recovery diode (25 ns typ.) in one package
- Trench gate and thin wafer technology
- High speed switching t_f = 110 ns typ. (at V_{CC} = 300 V, V_{GE} = 15 V, I_C = 8 A, Rg = 5 $\Omega,$ inductive load)

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item		Symbol	Ratings	Unit
Collector to emitter voltage / diode reverse voltage		V _{CES} / V _R	600	V
Gate to emitter voltage		V_{GES}	±30	V
Collector current	Tc = 25°C	I _C	16	А
	Tc = 100°C	I _C	8	А
Collector peak current		ic(peak) Note1	32	А
Collector to emitter diode forward current		i _{DF}	8	А
Collector to emitter diode forward peak current		i _D (peak) Note1	32	А
Collector dissipation		P _C Note2	30	W
Junction to case thermal resistance (IGBT)		θj-c ^{Note2}	4.1	°C/W
Junction to case thermal resistance (Diode)		θj-cd Note2	2.5	°C/W
Junction temperature		Tj	150	°C
Storage temperature		Tstg	-55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

2. Value at Tc = 25°C

Electrical Characteristics

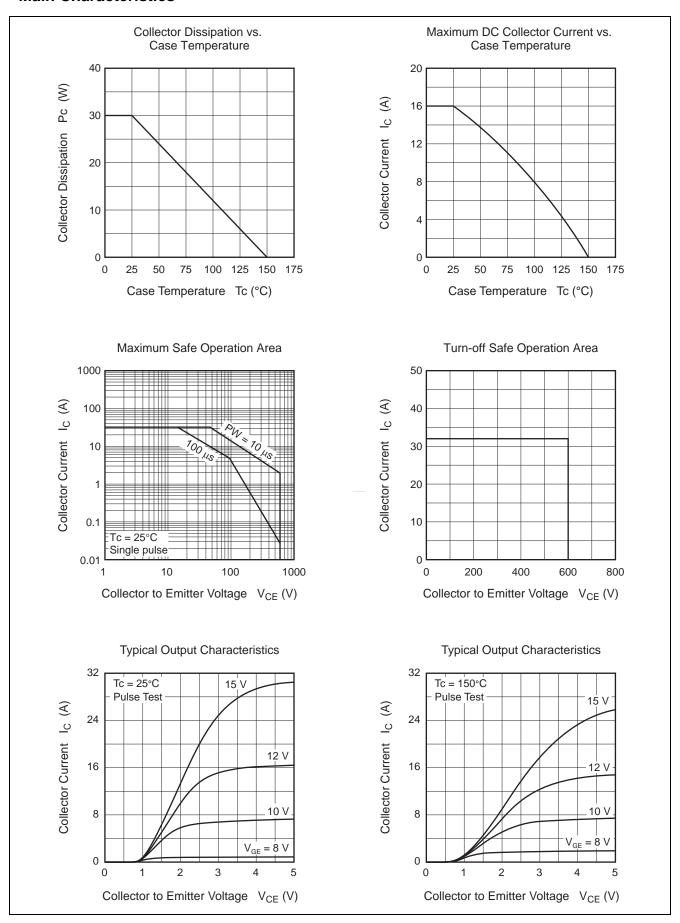
 $(Ta = 25^{\circ}C)$

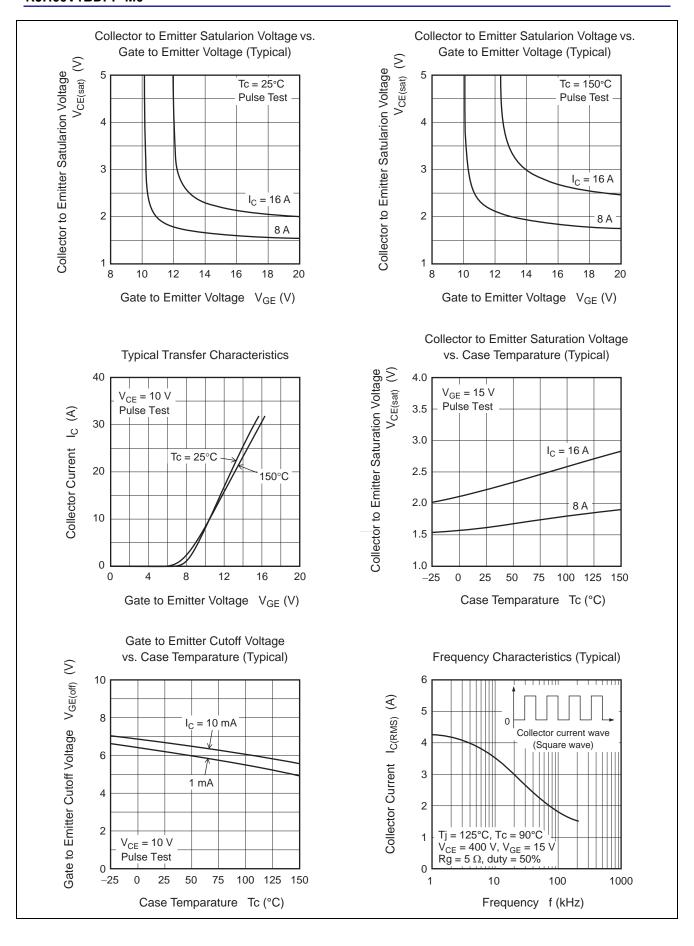
Item	Symbol	Min	Тур	Max	Unit	Test Conditions	
Collector to emitter breakdown voltage	V _{(BR)CES}	600	_	_	V	$I_C = 10 \mu A, V_{GE} = 0$	
Zero gate voltage collector current / Diode reverse current	I _{CES} / I _R	_	_	5	μА	V _{CE} = 600 V, V _{GE} = 0	
Gate to emitter leak current	I _{GES}	_	_	±1	μΑ	$V_{GE} = \pm 30 \text{ V}, V_{CE} = 0$	
Gate to emitter cutoff voltage	$V_{\text{GE(off)}}$	5.5	_	7.5	V	$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}$	
Collector to emitter saturation voltage	$V_{CE(sat)}$	_	1.6	2.2	V	$I_C = 8 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$	
	V _{CE(sat)}	_	2.2		V	$I_C = 16 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$	
Input capacitance	Cies	_	300		pF	V _{CE} = 25 V	
Output capacitance	Coes	_	27	_	pF	$V_{GE} = 0$	
Reverse transfer capacitance	Cres	_	12	_	pF	f = 1 MHz	
Total gate charge	Qg	_	19	_	nC	V _{GE} = 15 V V _{CE} = 300 V I _C = 8 A	
Gate to emitter charge	Qge	_	3.5	_	nC		
Gate to collector charge	Qgc	_	11	_	nC		
Turn-on delay time	t _{d(on)}	_	30	_	ns	V _{CC} = 300 V V _{GE} = 15 V	
Rise time	t _r	_	12	_	ns		
Turn-off delay time	t _{d(off)}	_	55	_	ns	I _C = 8 A	
Fall time	t _f	_	110	_	ns	$Rg = 5 \Omega$	
Turn-on energy	Eon	_	0.017	_	mJ	(Inductive load)	
Turn-off energy	E _{off}	_	0.11	_	mJ		
Total switching energy	E _{total}	_	0.13	_	mJ	1	
Short circuit withstand time	t _{sc}	3	6	_	μS	Tc = 100 °C	
						$V_{GE}\leq360~V,V_{GE}=15~V$	
		I	T 0.5	1		L a Note3	
FRD Forward voltage	V _F	_	2.5		V	I _F = 8 A ^{Note3}	
FRD reverse recovery time	t _{ee}		25	l —	ns	I_ = 8 A	

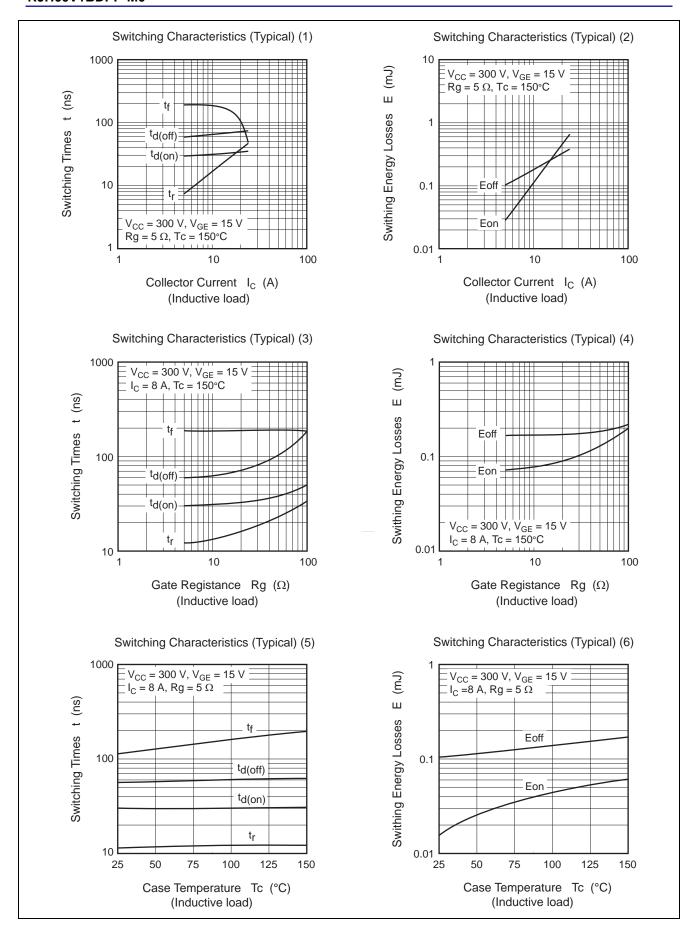
FRD Forward voltage	V_{F}	_	2.5	_	V	$I_F = 8 A^{\text{Note3}}$
FRD reverse recovery time	t _{rr}	_	25	_	ns	I _F = 8 A
FRD reverse recovery charge	Qrr	_	0.01		μС	di _F /dt = 100 A/μs
FRD peak reverse recovery current	Im	_	1.0	_	Α	

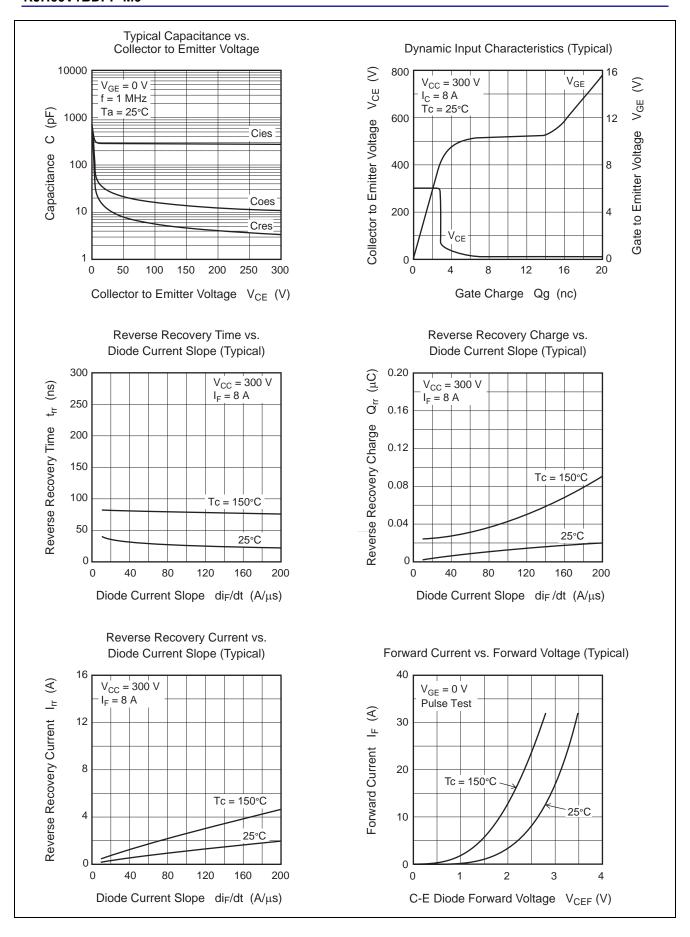
Notes: 3. Pulse test.

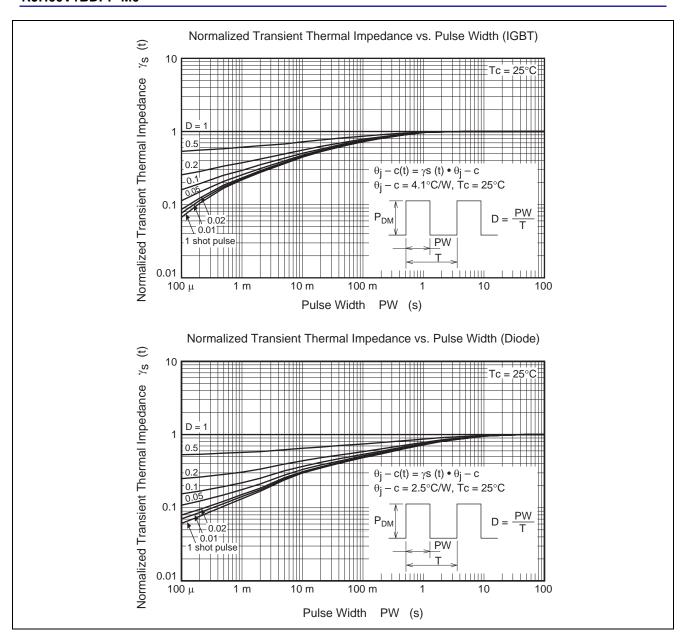
Main Characteristics

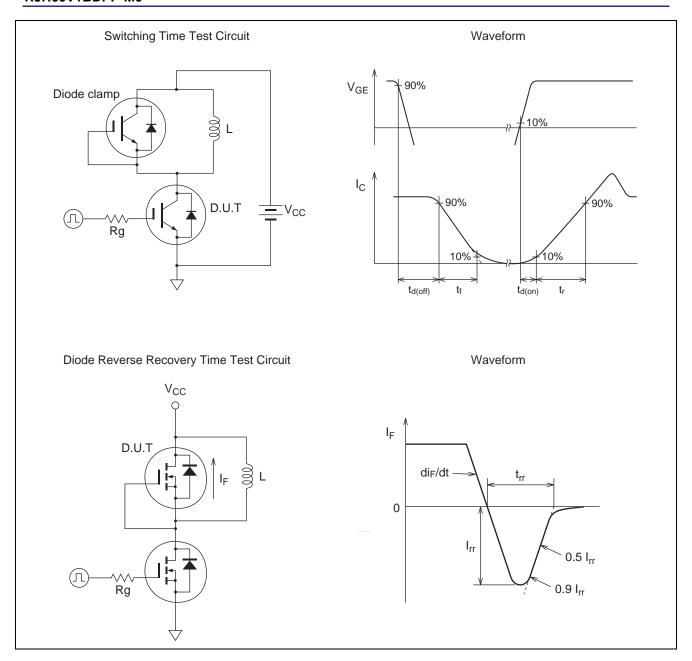




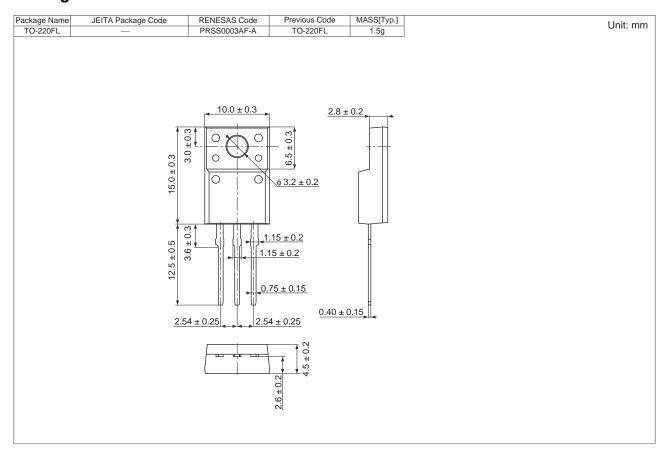








Package Dimension



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJH60V1BDPP-M0#T2	600 pcs	Box (Tube)

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